NSN 5961-01-067-3031

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-067-3031 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.3 millimeters **Overall Diameter:** 2.5 millimeters **End Application:** 485l tacs **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 collector to base voltage/static/emitter open and 16.0 collector to emitter voltage/static/base open and 1.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Weapon system essential; junction pattern arrangement: npn **Terminal Type And Quantity:** 2 tab, solder lug and 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No